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PTO/SB/08A (08-00)

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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>			Complete If Known		
			Application Number		
			Filing Date		
			First Named Inventor		
			Group Art Unit		
			Examiner Name		
Sheet	1	of	2	Attorney Docket Number	
				MXIC 1564-1	

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
<i>EPR</i>	A1	4,959,812		Momodomi et al.	09-25-1990	
<i>EPR</i>	A2	5,270,969		Iwahashi	12-14-1993	
<i>EPR</i>	A3	5,424,569		Prall	06-13-1995	
<i>EPR</i>	A4	5,448,517		Tanaka	05-07-1996	
<i>EPR</i>	A5	5,644,533		Lancaster et al.	07-01-1997	
<i>EPR</i>	A6	5,768,192		Eitan	06-16-1998	
<i>EPR</i>	A7	6,011,725		Eitan	01-04-2000	
<i>EPR</i>	A8	6,172,907		Jenne	01-09-2001	
<i>EPR</i>	A9	6,215,148		Eitan	04-10-2001	
<i>EPR</i>	A10	6,436,768		Yang et al.	08-20-2002	
<i>EPR</i>	A11	6,458,642		Yeh et al.	10-01-2002	
<i>EPR</i>	A12	Re. 35,838		Momodomi et al.	07-07-1998	
<i>EPR</i>	A13	2002/0179958		Kim	12-05-2002	
	A14					
	A15					
	A16					
	A17					
	A18					
	A19					
	A20					

FOREIGN PATENT DOCUMENTS								
Examiner Initials*	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁵
		Office ³	Number ⁴	Kind Code ⁵ (if known)				
	B1							
	B2							
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	B5							
	B6							
	B7							
	B8							
	B9							
	B10							

Examiner Signature	<i>E. J. Henderson</i>	Date Considered	8/18/05
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Substitute for form 1449B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)			Complete if Known	
			Application Number	
			Filing Date	3 February 2004 (herewith)
			First Named Inventor	Hsiang Lan Lung
			Group Art Unit	
			Examiner Name	
Sheet	2	of		Attorney Docket Number MXIC 1564-1

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
EJW	C1	DE BLAUWE, JAN, "Nanocrystal Nonvolatile Memory Devices," IEEE Transactions on Nanotechnology, Vol. 1, No. 1 (March 2002) 72-77	
EJW	C2	LEE, JAE-DUK, "Effects of Floating-Gate Interference on NAND Flash Memory Cell Operation," IEEE Electron Device Letters, Vol. 23, No. 5 (May 2002), 264-266	
EJW	C3	LEE, CHANGHYUN, et al., "A Novel Structure of SiO ₂ /SiN/High k Dielectrics, Al ₂ O ₃ for SONOS Type Flash Memory," Extended Abstracts of the 2002 International Conference on Solid State Device and Materials, Nagoya (2002), 162-163.	
EJW	C4	SHIN, YOOCHEOL, et al., "High Reliable SONOS-Type NAND Flash Memory Cell with Al ₂ O ₃ for Top Oxide," Non-Volatile Semiconductor Memory Workshop (2003) 2 pages	
EJW	C5	LEE, CHANG HYUN, et al., "A Novel SONOS Structure of SiO ₂ /SiN/Al ₂ O ₃ with TaN Metal Gate for Multi-Giga Bit Flash Memories," IEEE (2003) 4 pages.	
EJW	C6	CHUNG, STEVE S., et al., "A Novel Leakage Current Separation Technique in a Direct Tunneling Regime Gate Oxide SONOS Memory Cell," IEEE (2003), 4 pages.	
EJW	C7	HIROSE, M., "Challenges for Future Semiconductor Development," Advance Semiconductor Research Center, National Institute for Advanced Industrial Science and Technology, International Microprocess and Nanotechnology Conference, (6 Nov. 2002), available at http://www.miraipj.jp/en/opendata/pdf/021106MNC.pdf . NO COPY OF DOCUMENT PROVIDED, WEBSITE HAS DOCUMENT LOCKED, CAN ONLY VIEW ON INTERNET	

Examiner Signature	<i>E. J. Ward</i>	Date Considered	8/18/05
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Substitute for form 1449/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Complete if Known

Application Number	10/771,023
Filing Date	3 February 2004
First Named Inventor	HSIANG LAN LUNG
Art Unit	Not assigned
Examiner Name	Not assigned
Attorney Docket Number	MXIC 1564-1

Sheet	1	of	1
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U. S. PATENT DOCUMENTS

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FOREIGN PATENT DOCUMENTS

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